



1995 IEEE GaAs IC Symposium

INTEGRATED CIRCUITS IN GaAs, InP, and OTHER COMPOUND SEMICONDUCTORS



Co-Sponsored by the IEEE Electron Devices and Microwave Theory & Techniques Societies



October 29-November 1, 1995

Sheraton Harbor Island Hotel, San Diego, CA

CALL FOR PAPERS, ABSTRACT DEADLINE: May 5, 1995

Over the last 17 years, the IEEE GaAs IC Symposium has become the preeminent international forum on the most recent developments in integrated circuits using GaAs, InP, and other compound semiconductor devices. Coverage embraces all aspects of the technology including materials issues, device fabrication, IC design and testing, volume manufacturing, and systems implementation. High-quality, first-time submissions are sought in the fields of high-speed digital, analog, microwave/millimeter wave, mixed mode, and optoelectronic integrated circuits. Areas of interest include:

Circuit Fabrication

Reliability

Advanced Device Applications

Wireless Applications

Circuit Design

Device/Circuit Modeling

IC Testing

High Speed Digital IC's

Manufacturing

Packaging Technology

OEIC's

Micro/mm Wave IC's

SYMPOSIUM HIGHLIGHTS

Based on past history, it is anticipated that over 70 technical papers will be selected representing countries around the world. In addition to oral presentation, these papers will be published in the Symposium Digest. In addition, there will be several invited papers and panel sessions on topics of current importance to the GaAs IC technical community including both suppliers and customers. For further information on the symposium content please contact Ellisa Sobolewski, Advanced Research Projects Agency, Phone (703) 696-2254, FAX (703) 696-2203.

GUIDELINES FOR ABSTRACT SUBMISSION **DEADLINE: RECEIPT BY CLOSE OF BUSINESS May 5, 1995**

Authors must submit one-page abstracts of results not previously published or not already accepted by another conference. Additional supporting material (2-page maximum) may also be submitted at the discretion of the authors. Papers will be selected on the basis of the abstract which should concisely and clearly state (a) The purpose of the work, (b) What specific new results have been obtained, and (c) How much it advances the state of the art. The abstract and supporting material should be typewritten on one side of the paper only, and must include: title, name(s) of the author(s), organization(s) represented, and mailing address and telephone and FAX numbers of the first author.

Mail forty (40) copies of a one-page abstract and any supporting material to:

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